## NSN 5962-01-420-4637

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Between 0.441 inches and 0.460 inches

**Body Width:** 

Between 0.442 inches and 0.460 inches

**Body Height:** 

Between 0.060 inches and 0.100 inches

**Maximum Power Dissipation Rating:** 

1.2 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Pacer dawn

#### **Features Provided:**

Electrostatic sensitive and hermetically sealed and burn in and programmed and monolithic

#### **Inclosure Material:**

Ceramic

## **Inclosure Configuration:**

Leadless flat pack

## **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

#### **Input Circuit Pattern:**

22 input

## **Criticality Code Justification:**

Cbbl

## **Case Outline Source And Designator:**

C-4 mil-m-38510

## **Terminal Surface Treatment:**

Solder

#### **Product Name:**

Microcircuit, programmed (pal c22v10-25)

## **Voltage Rating And Type Per Characteristic:**

-0.5 volts power source and 7.0 volts power source

### **Memory Device Type:**

Pal

## **Special Features:**

Altered item; made from device 5962-88670013a, microcircuit, memory, digital, cmos, one-time programmable, programmable array logic, monolithic silicon

#### **Test Data Document:**

96906-mil-std883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## **Terminal Type And Quantity:**

28 leadless

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Shelf	LIIE.

N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

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